Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	C166
Core Size	16-Bit
Speed	20MHz
Connectivity	EBI/EMI, SPI, UART/USART
Peripherals	POR, PWM, WDT
Number of I/O	77
Program Memory Size	-
Program Memory Type	ROMless
EEPROM Size	-
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	4.5V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-BQFP
Supplier Device Package	P-MQFP-100
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/c165lmhafxuma1

C165

- High Performance 16-bit CPU with 4-Stage Pipeline
  - 80 ns Instruction Cycle Time at 25 MHz CPU Clock
  - 400 ns Multiplication (16 × 16 bit), 800 ns Division (32 / 16 bit)
  - Enhanced Boolean Bit Manipulation Facilities
  - Additional Instructions to Support HLL and Operating Systems
  - Register-Based Design with Multiple Variable Register Banks
  - Single-Cycle Context Switching Support
  - 16 MBytes Total Linear Address Space for Code and Data
  - 1024 Bytes On-Chip Special Function Register Area
- 16-Priority-Level Interrupt System with 28 Sources, Sample-Rate down to 40 ns
- 8-Channel Interrupt-Driven Single-Cycle Data Transfer Facilities via Peripheral Event Controller (PEC)
- Clock Generation via prescaler or via direct clock input
- On-Chip Memory Modules
  - 2 KBytes On-Chip Internal RAM (IRAM)
- On-Chip Peripheral Modules
  - Two Multi-Functional General Purpose Timer Units with 5 Timers
  - Two Serial Channels (Synchronous/Asynchronous and High-Speed-Synchronous)
- Up to 16 MBytes External Address Space for Code and Data
  - Programmable External Bus Characteristics for Different Address Ranges
  - Multiplexed or Demultiplexed External Address/Data Buses with 8-Bit or 16-Bit Data Bus Width
  - Five Programmable Chip-Select Signals
  - Hold- and Hold-Acknowledge Bus Arbitration Support
- Idle and Power Down Modes
- Programmable Watchdog Timer
- Up to 77 General Purpose I/O Lines, partly with Selectable Input Thresholds and Hysteresis
- Power Supply: the C165 can operate from a 5 V or a 3 V power supply
- Supported by a Large Range of Development Tools like C-Compilers, Macro-Assembler Packages, Emulators, Evaluation Boards, HLL-Debuggers, Simulators, Logic Analyzer Disassemblers, Programming Boards
- On-Chip Bootstrap Loader
- 100-Pin MQFP Package (0.65 mm pitch)
- 100-Pin TQFP Package (0.5 mm pitch)

Pin Configuration MQFP Package
(top view)

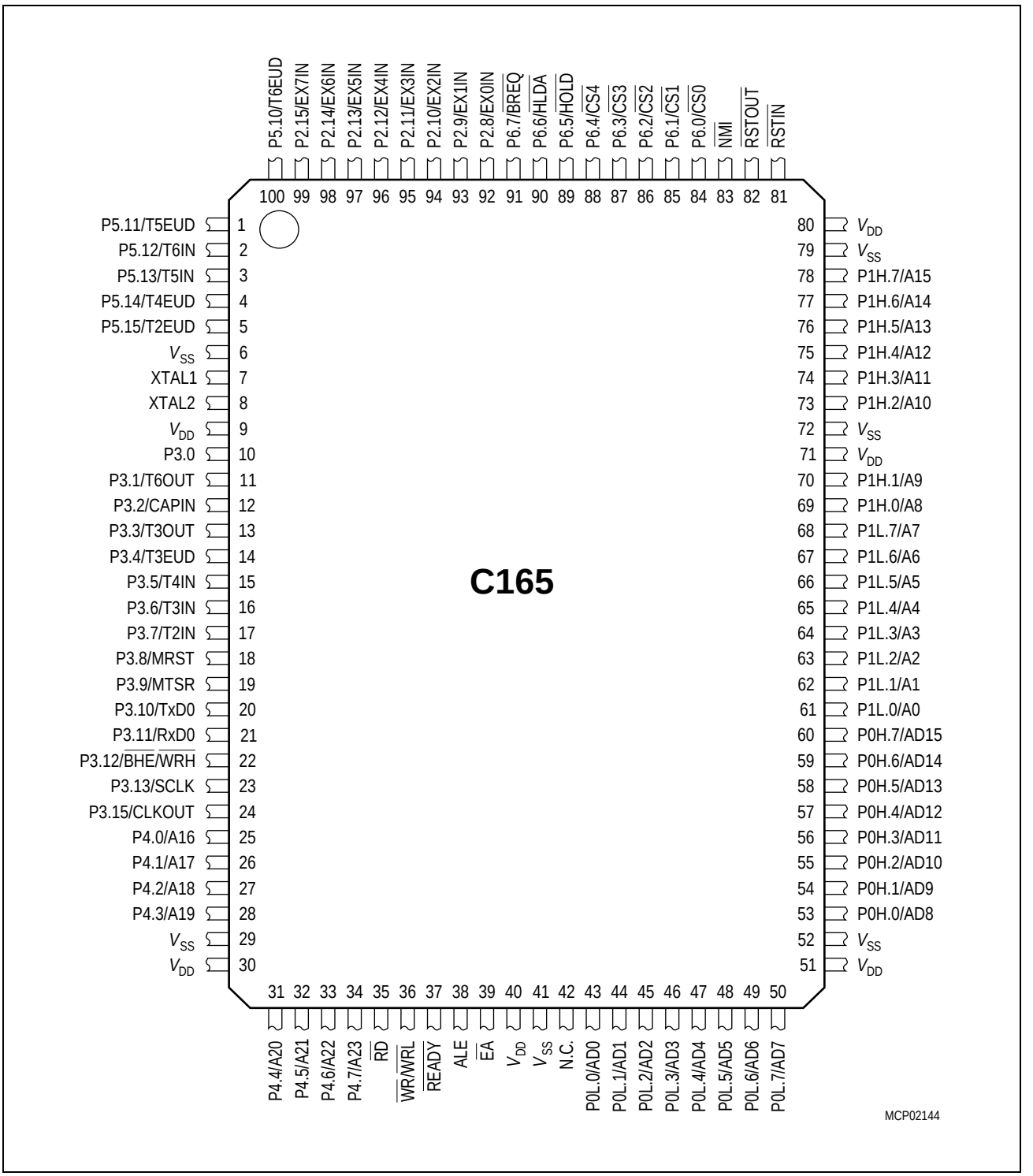


Figure 3

Table 2 Pin Definitions and Functions (cont'd)

Symbol	Pin Nr TQFP	Pin Nr MQFP	Input Outp.	Function
NC	40	42	–	This pin is not connected in the C165. No connection to the PCB is required.
PORT0 P0L.0-7 P0H.0-7	 41-48 51-58	 43-50 53-60	IO	PORT0 consists of the two 8-bit bidirectional I/O ports P0L and P0H. It is bit-wise programmable for input or output via direction bits. For a pin configured as input, the output driver is put into high-impedance state. In case of an external bus configuration, PORT0 serves as the address (A) and address/data (AD) bus in multiplexed bus modes and as the data (D) bus in demultiplexed bus modes. **Demultiplexed bus modes:** Data Path Width: 8-bit 16-bit P0L.0 – P0L.7: D0 – D7 D0 – D7 P0H.0 – P0H.7: I/O D8 – D15 **Multiplexed bus modes:** Data Path Width: 8-bit 16-bit P0L.0 – P0L.7: AD0 – AD7 AD0 – AD7 P0H.0 – P0H.7: A8 – A15 AD8 – AD15
PORT1 P1L.0-7 P1H.0-7	 59-66 67,68, 71-76	 61-68 69-70, 73-78	IO	PORT1 consists of the two 8-bit bidirectional I/O ports P1L and P1H. It is bit-wise programmable for input or output via direction bits. For a pin configured as input, the output driver is put into high-impedance state. PORT1 is used as the 16-bit address bus (A) in demultiplexed bus modes and also after switching from a demultiplexed bus mode to a multiplexed bus mode.

Table 2 Pin Definitions and Functions (cont'd)

Symbol	Pin Nr TQFP	Pin Nr MQFP	Input Outp.	Function
$\overline{\text{RSTIN}}$	79	81	I/O	Reset Input with Schmitt-Trigger characteristics. A low level at this pin while the oscillator is running resets the C165. An internal pullup resistor permits power-on reset using only a capacitor connected to V_{SS}. A spike filter suppresses input pulses < 10 ns. Input pulses >100 ns safely pass the filter. The minimum duration for a safe recognition should be 100 ns + 2 CPU clock cycles. In bidirectional reset mode (enabled by setting bit BDRSTEN in register SYSCON) the $\overline{\text{RSTIN}}$ line is internally pulled low for the duration of the internal reset sequence upon any reset (HW, SW, WDT). See note below this table. *Note: To let the reset configuration of PORT0 settle a reset duration of ca. 1 ms is recommended.*
$\overline{\text{RSTOUT}}$	80	82	O	Internal Reset Indication Output. This pin is set to a low level when the part is executing either a hardware-, a software- or a watchdog timer reset. $\overline{\text{RSTOUT}}$ remains low until the EINIT (end of initialization) instruction is executed.
$\overline{\text{NMI}}$	81	83	I	Non-Maskable Interrupt Input. A high to low transition at this pin causes the CPU to vector to the NMI trap routine. When the PWRDN (power down) instruction is executed, the $\overline{\text{NMI}}$ pin must be low in order to force the C165 to go into power down mode. If $\overline{\text{NMI}}$ is high, when PWRDN is executed, the part will continue to run in normal mode. If not used, pin $\overline{\text{NMI}}$ should be pulled high externally.

Table 2 Pin Definitions and Functions (cont'd)

Symbol	Pin Nr TQFP	Pin Nr MQFP	Input Outp.	Function
P6			IO	Port 6 is an 8-bit bidirectional I/O port. It is bit-wise programmable for input or output via direction bits. For a pin configured as input, the output driver is put into high-impedance state. Port 6 outputs can be configured as push/pull or open drain drivers. The Port 6 pins also serve for alternate functions:
P6.0	82	84	O	$\overline{CS0}$ Chip Select 0 Output
P6.1	83	85	O	$\overline{CS1}$ Chip Select 1 Output
P6.2	84	86	O	$\overline{CS2}$ Chip Select 2 Output
P6.3	85	87	O	$\overline{CS3}$ Chip Select 3 Output
P6.4	86	88	O	$\overline{CS4}$ Chip Select 4 Output
P6.5	87	89	I	$\overline{HOLD}$ External Master Hold Request Input
P6.6	88	90	I/O	$\overline{HLDA}$ Hold Acknowledge Outp.(master mode) or Input (slave mode)
P6.7	89	91	O	$\overline{BREQ}$ Bus Request Output
P2			IO	Port 2 is an 8-bit bidirectional I/O port. It is bit-wise programmable for input or output via direction bits. For a pin configured as input, the output driver is put into high-impedance state. Port 2 outputs can be configured as push/pull or open drain drivers. The following Port 2 pins serve for alternate functions:
P2.8	90	92	I	EX0IN Fast External Interrupt 0 Input
P2.9	91	93	I	EX1IN Fast External Interrupt 1 Input
P2.10	92	94	I	EX2IN Fast External Interrupt 2 Input
P2.11	93	95	I	EX3IN Fast External Interrupt 3 Input
P2.12	94	96	I	EX4IN Fast External Interrupt 4 Input
P2.13	95	97	I	EX5IN Fast External Interrupt 5 Input
P2.14	96	98	I	EX6IN Fast External Interrupt 6 Input
P2.15	97	99	I	EX7IN Fast External Interrupt 7 Input
P5			I	Port 5 is a 6-bit input-only port with Schmitt-Trigger char. The pins of Port 5 also serve as timer inputs:
P5.10	98	100	I	T6EUD GPT2 Timer T6 Ext. Up/Down Ctrl Input
P5.11	99	1	I	T5EUD GPT2 Timer T5 Ext. Up/Down Ctrl Input
P5.12	100	2	I	T6IN GPT2 Timer T6 Count Input
P5.13	1	3	I	T5IN GPT2 Timer T5 Count Input
P5.14	2	4	I	T4EUD GPT1 Timer T4 Ext. Up/Down Ctrl Input
P5.15	3	5	I	T2EUD GPT1 Timer T2 Ext. Up/Down Ctrl Input

Functional Description

The architecture of the C165 combines advantages of both RISC and CISC processors and of advanced peripheral subsystems in a very well-balanced way. In addition the on-chip memory blocks allow the design of compact systems with maximum performance.
The following block diagram gives an overview of the different on-chip components and of the advanced, high bandwidth internal bus structure of the C165.

Note: All time specifications refer to a CPU clock of 25 MHz (see definition in the AC Characteristics section).

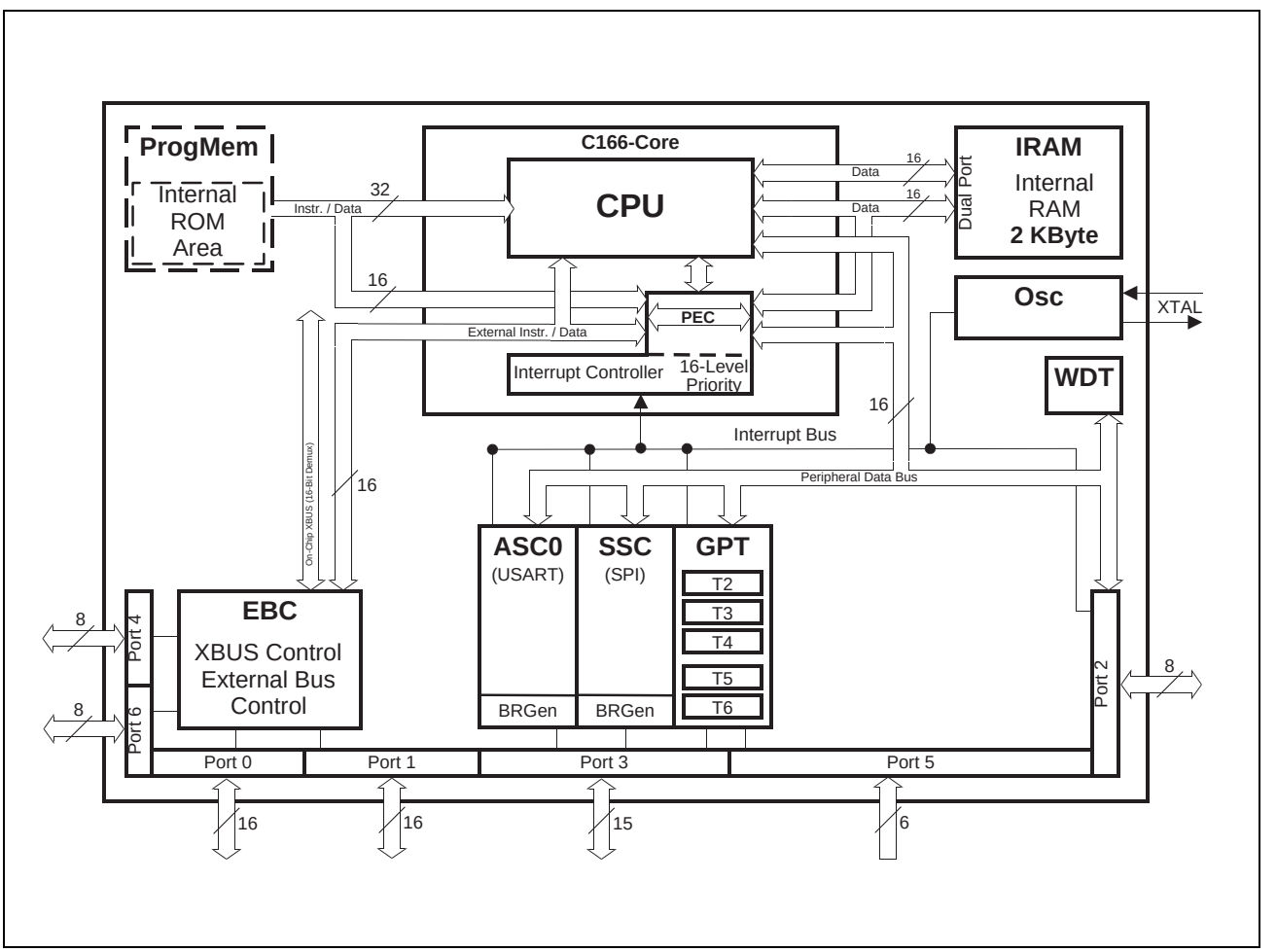


Figure 4 Block Diagram

The program memory, the internal RAM (IRAM) and the set of generic peripherals are connected to the CPU via separate buses. A fourth bus, the XBUS, connects external resources as well as additional on-chip resoures, the X-Peripherals (see **Figure 4**).

General Purpose Timer (GPT) Unit

The GPT unit represents a very flexible multifunctional timer/counter structure which may be used for many different time related tasks such as event timing and counting, pulse width and duty cycle measurements, pulse generation, or pulse multiplication.

The GPT unit incorporates five 16-bit timers which are organized in two separate modules, GPT1 and GPT2. Each timer in each module may operate independently in a number of different modes, or may be concatenated with another timer of the same module.

Each of the three timers T2, T3, T4 of **module GPT1** can be configured individually for one of four basic modes of operation, which are Timer, Gated Timer, Counter, and Incremental Interface Mode. In Timer Mode, the input clock for a timer is derived from the CPU clock, divided by a programmable prescaler, while Counter Mode allows a timer to be clocked in reference to external events.
Pulse width or duty cycle measurement is supported in Gated Timer Mode, where the operation of a timer is controlled by the ‘gate’ level on an external input pin. For these purposes, each timer has one associated port pin (TxIN) which serves as gate or clock input. The maximum resolution of the timers in module GPT1 is 16 TCL.

The count direction (up/down) for each timer is programmable by software or may additionally be altered dynamically by an external signal on a port pin (TxEUD) to facilitate e.g. position tracking.

In Incremental Interface Mode the GPT1 timers (T2, T3, T4) can be directly connected to the incremental position sensor signals A and B via their respective inputs TxIN and TxEUD. Direction and count signals are internally derived from these two input signals, so the contents of the respective timer Tx corresponds to the sensor position. The third position sensor signal TOP0 can be connected to an interrupt input.

Timer T3 has an output toggle latch (T3OTL) which changes its state on each timer over-flow/underflow. The state of this latch may be output on pin T3OUT e.g. for time out monitoring of external hardware components, or may be used internally to clock timers T2 and T4 for measuring long time periods with high resolution.

In addition to their basic operating modes, timers T2 and T4 may be configured as reload or capture registers for timer T3. When used as capture or reload registers, timers T2 and T4 are stopped. The contents of timer T3 is captured into T2 or T4 in response to a signal at their associated input pins (TxIN). Timer T3 is reloaded with the contents of T2 or T4 triggered either by an external signal or by a selectable state transition of its toggle latch T3OTL. When both T2 and T4 are configured to alternately reload T3 on opposite state transitions of T3OTL with the low and high times of a PWM signal, this signal can be constantly generated without software intervention.

The capture trigger (timer T5 to CAPREL) may also be generated upon transitions of GPT1 timer T3's inputs T3IN and/or T3EUD. This is especially advantageous when T3 operates in Incremental Interface Mode.

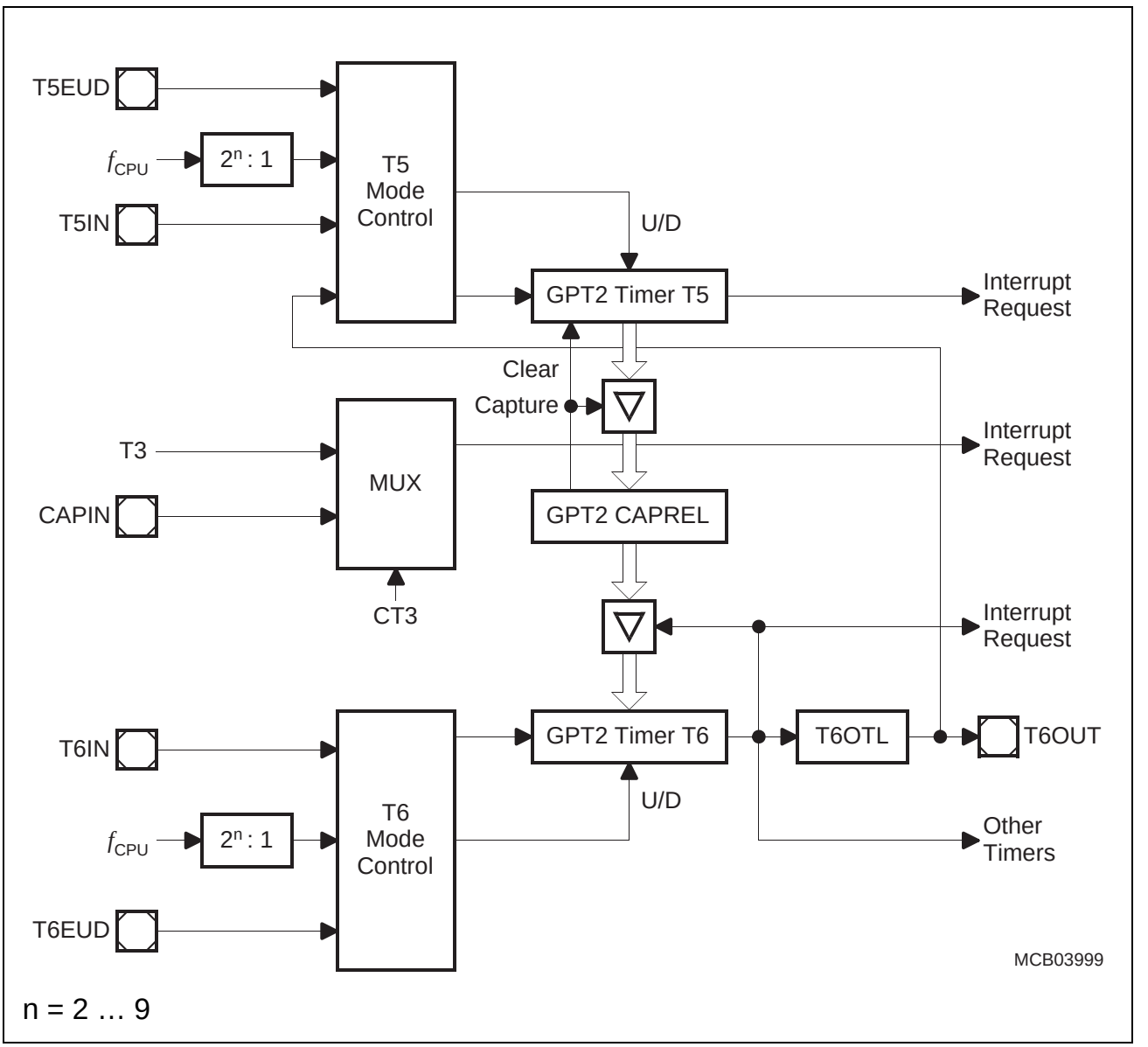


Figure 7 Block Diagram of GPT2

Parameter Interpretation

The parameters listed in the following partly represent the characteristics of the C165 and partly its demands on the system. To aid in interpreting the parameters right, when evaluating them for a design, they are marked in column “Symbol”:

CC (**C**ontroller **C**haracteristics):
The logic of the C165 will provide signals with the respective timing characteristics.

SR (**S**ystem **R**equirement):
The external system must provide signals with the respective timing characteristics to the C165.

DC Characteristics (Standard Supply Voltage Range)

(Operating Conditions apply)[1)]

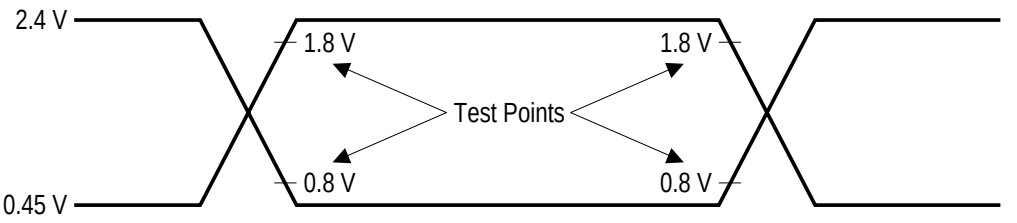
Parameter	Symbol	Limit Values		Unit	Test Condition
		min.	max.		
Input low voltage (TTL, all except XTAL1)	V_{IL} SR	– 0.5	0.2 V_{DD} – 0.1	V	–
Input low voltage XTAL1	V_{IL2} SR	– 0.5	0.3 V_{DD}	V	–
Input high voltage (TTL, all except $\overline{\text{RSTIN}}$ and XTAL1)	V_{IH} SR	0.2 V_{DD} + 0.9	V_{DD} + 0.5	V	–
Input high voltage $\overline{\text{RSTIN}}$ (when operated as input)	V_{IH1} SR	0.6 V_{DD}	V_{DD} + 0.5	V	–
Input high voltage XTAL1	V_{IH2} SR	0.7 V_{DD}	V_{DD} + 0.5	V	–
Output low voltage ($\overline{\text{PORT0}}$, $\overline{\text{PORT1}}$, Port 4, ALE, $\overline{\text{RD}}$, $\overline{\text{WR}}$, $\overline{\text{BHE}}$, $\overline{\text{RSTOUT}}$, $\overline{\text{RSTIN}}$[2)])	V_{OL} CC	–	0.45	V	I_{OL} = 2.4 mA
Output low voltage (all other outputs)	V_{OL1} CC	–	0.45	V	I_{OL} = 1.6 mA
Output high voltage[3)] ($\overline{\text{PORT0}}$, $\overline{\text{PORT1}}$, Port 4, ALE, $\overline{\text{RD}}$, $\overline{\text{WR}}$, $\overline{\text{BHE}}$, $\overline{\text{RSTOUT}}$)	V_{OH} CC	2.4	–	V	I_{OH} = - 2.4 mA
		0.9 V_{DD}	–	V	I_{OH} = - 0.5 mA
Output high voltage[3)] (all other outputs)	V_{OH1} CC	2.4	–	V	I_{OH} = - 1.6 mA
		0.9 V_{DD}	–	V	I_{OH} = - 0.5 mA
Input leakage current (Port 5)	I_{OZ1} CC	–	± 200	nA	0 V < V_{IN} < V_{DD}
Input leakage current (all other)	I_{OZ2} CC	–	± 500	nA	0.45 V < V_{IN} < V_{DD}
$\overline{\text{RSTIN}}$ inactive current[4)]	I_{RSTH}[5)]	–	- 10	µA	V_{IN} = V_{IH1}

DC Characteristics (Reduced Supply Voltage Range)

(Operating Conditions apply)[1)]

Parameter	Symbol	Limit Values		Unit	Test Condition
		min.	max.		
Input low voltage (TTL, all except XTAL1)	V_{IL} SR	- 0.5	0.8	V	–
Input low voltage XTAL1	V_{IL2} SR	- 0.5	0.3 V_{DD}	V	–
Input high voltage (TTL, all except $\overline{\text{RSTIN}}$ and XTAL1)	V_{IH} SR	1.8	V_{DD} + 0.5	V	–
Input high voltage $\overline{\text{RSTIN}}$ (when operated as input)	V_{IH1} SR	0.6 V_{DD}	V_{DD} + 0.5	V	–
Input high voltage XTAL1	V_{IH2} SR	0.7 V_{DD}	V_{DD} + 0.5	V	–
Output low voltage (PORT0, PORT1, Port 4, ALE, $\overline{\text{RD}}$, $\overline{\text{WR}}$, $\overline{\text{BHE}}$, $\overline{\text{RSTOUT}}$, $\overline{\text{RSTIN}}$[2)])	V_{OL} CC	–	0.45	V	I_{OL} = 1.6 mA
Output low voltage (all other outputs)	V_{OL1} CC	–	0.45	V	I_{OL} = 1.0 mA
Output high voltage[3)] (PORT0, PORT1, Port 4, ALE, $\overline{\text{RD}}$, $\overline{\text{WR}}$, $\overline{\text{BHE}}$, $\overline{\text{RSTOUT}}$)	V_{OH} CC	0.9 V_{DD}	–	V	I_{OH} = - 0.5 mA
Output high voltage[3)] (all other outputs)	V_{OH1} CC	0.9 V_{DD}	–	V	I_{OH} = - 0.25 mA
Input leakage current (Port 5)	I_{OZ1} CC	–	± 200	nA	0 V < V_{IN} < V_{DD}
Input leakage current (all other)	I_{OZ2} CC	–	± 500	nA	0.45 V < V_{IN} < V_{DD}
$\overline{\text{RSTIN}}$ inactive current[4)]	I_{RSTH}[5)]	–	- 10	µA	V_{IN} = V_{IH1}
$\overline{\text{RSTIN}}$ active current[4)]	I_{RSTL}[6)]	- 100	–	µA	V_{IN} = V_{IL}
$\overline{\text{READY}}$/$\overline{\text{RD}}$/$\overline{\text{WR}}$ inact. current[7)]	I_{RWH}[5)]	–	- 10	µA	V_{OUT} = 2.4 V
$\overline{\text{READY}}$/$\overline{\text{RD}}$/$\overline{\text{WR}}$ active current[7)]	I_{RWL}[6)]	- 500	–	µA	V_{OUT} = V_{OLmax}
ALE inactive current[7)]	I_{ALEL}[5)]	–	20	µA	V_{OUT} = V_{OLmax}
ALE active current[7)]	I_{ALEH}[6)]	500	–	µA	V_{OUT} = 2.4 V
Port 6 inactive current[7)]	I_{P6H}[5)]	–	- 10	µA	V_{OUT} = 2.4 V
Port 6 active current[7)]	I_{P6L}[6)]	- 500	–	µA	V_{OUT} = V_{OL1max}

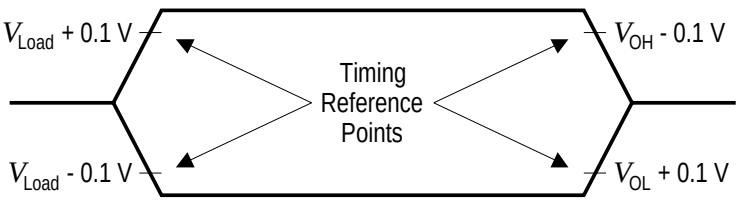
Testing Waveforms



AC inputs during testing are driven at 2.4 V for a logic ‘1’ and 0.45 V for a logic ‘0’.
Timing measurements are made at V_{IH} min for a logic ‘1’ and V_{IL} max for a logic ‘0’.

MCA04414

Figure 11 Input Output Waveforms



For timing purposes a port pin is no longer floating when a 100 mV change from load voltage occurs, but begins to float when a 100 mV change from the loaded V_{OH} / V_{OL} level occurs (I_{OH} / I_{OL} = 20 mA).

MCA00763

Figure 12 Float Waveforms

Multiplexed Bus (Standard Supply Voltage Range) (cont'd)
(Operating Conditions apply)
ALE cycle time = 6 TCL + $2t_A$ + t_C + t_F (120 ns at 25 MHz CPU clock without waitstates)

Parameter	Symbol		Max. CPU Clock = 25 MHz		Variable CPU Clock 1 / 2TCL = 1 to 25 MHz		Unit
			min.	max.	min.	max.	
Address float after $\overline{\text{RdCS}}$, $\overline{\text{WrCS}}$ (with RW delay)	t_{44}	CC	–	0	–	0	ns
Address float after $\overline{\text{RdCS}}$, $\overline{\text{WrCS}}$ (no RW delay)	t_{45}	CC	–	20	–	TCL	ns
$\overline{\text{RdCS}}$ to Valid Data In (with RW delay)	t_{46}	SR	–	16 + t_C	–	2TCL - 24 + t_C	ns
$\overline{\text{RdCS}}$ to Valid Data In (no RW delay)	t_{47}	SR	–	36 + t_C	–	3TCL - 24 + t_C	ns
$\overline{\text{RdCS}}$, $\overline{\text{WrCS}}$ Low Time (with RW delay)	t_{48}	CC	30 + t_C	–	2TCL - 10 + t_C	–	ns
$\overline{\text{RdCS}}$, $\overline{\text{WrCS}}$ Low Time (no RW delay)	t_{49}	CC	50 + t_C	–	3TCL - 10 + t_C	–	ns
Data valid to $\overline{\text{WrCS}}$	t_{50}	CC	26 + t_C	–	2TCL - 14 + t_C	–	ns
Data hold after $\overline{\text{RdCS}}$	t_{51}	SR	0	–	0	–	ns
Data float after $\overline{\text{RdCS}}$	t_{52}	SR	–	20 + t_F	–	2TCL - 20 + t_F	ns
Address hold after $\overline{\text{RdCS}}$, $\overline{\text{WrCS}}$	t_{54}	CC	20 + t_F	–	2TCL - 20 + t_F	–	ns
Data hold after $\overline{\text{WrCS}}$	t_{56}	CC	20 + t_F	–	2TCL - 20 + t_F	–	ns

1) These parameters refer to the latched chip select signals ($\overline{\text{CSxL}}$). The early chip select signals ($\overline{\text{CSxE}}$) are specified together with the address and signal $\overline{\text{BHE}}$ (see figures below).

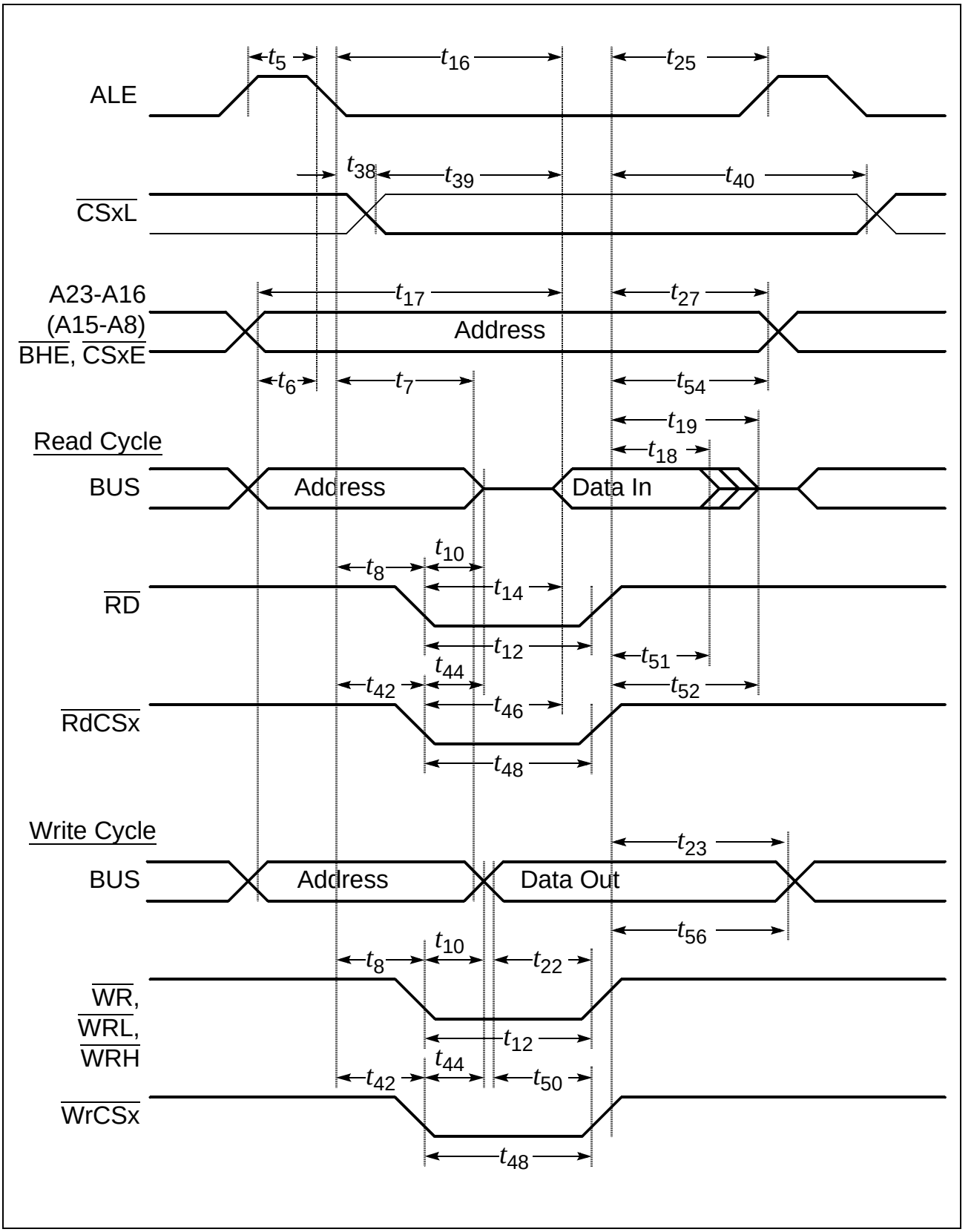


Figure 13 External Memory Cycle: Multiplexed Bus, With Read/Write Delay, Normal ALE

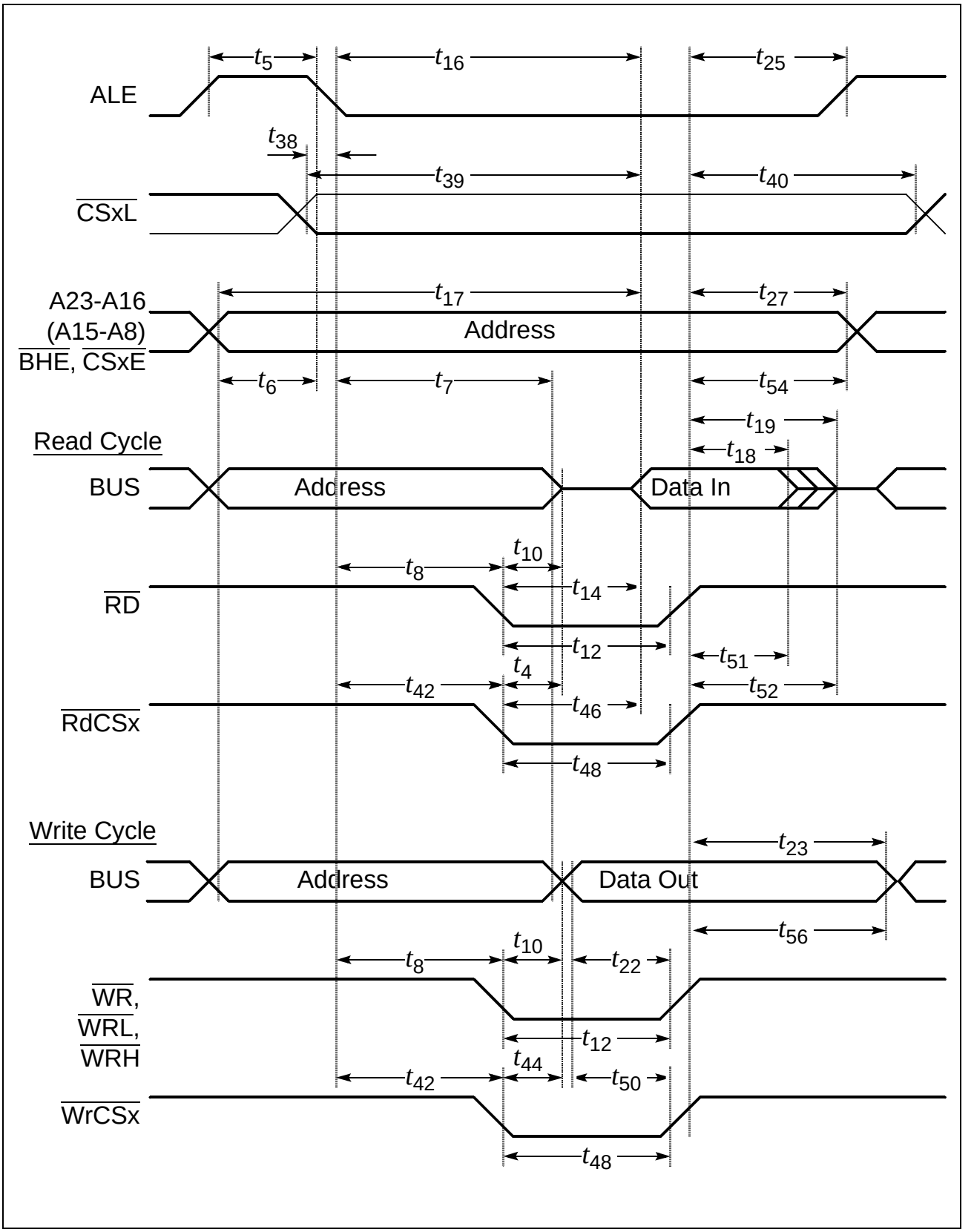


Figure 14 External Memory Cycle: Multiplexed Bus, With Read/Write Delay, Extended ALE

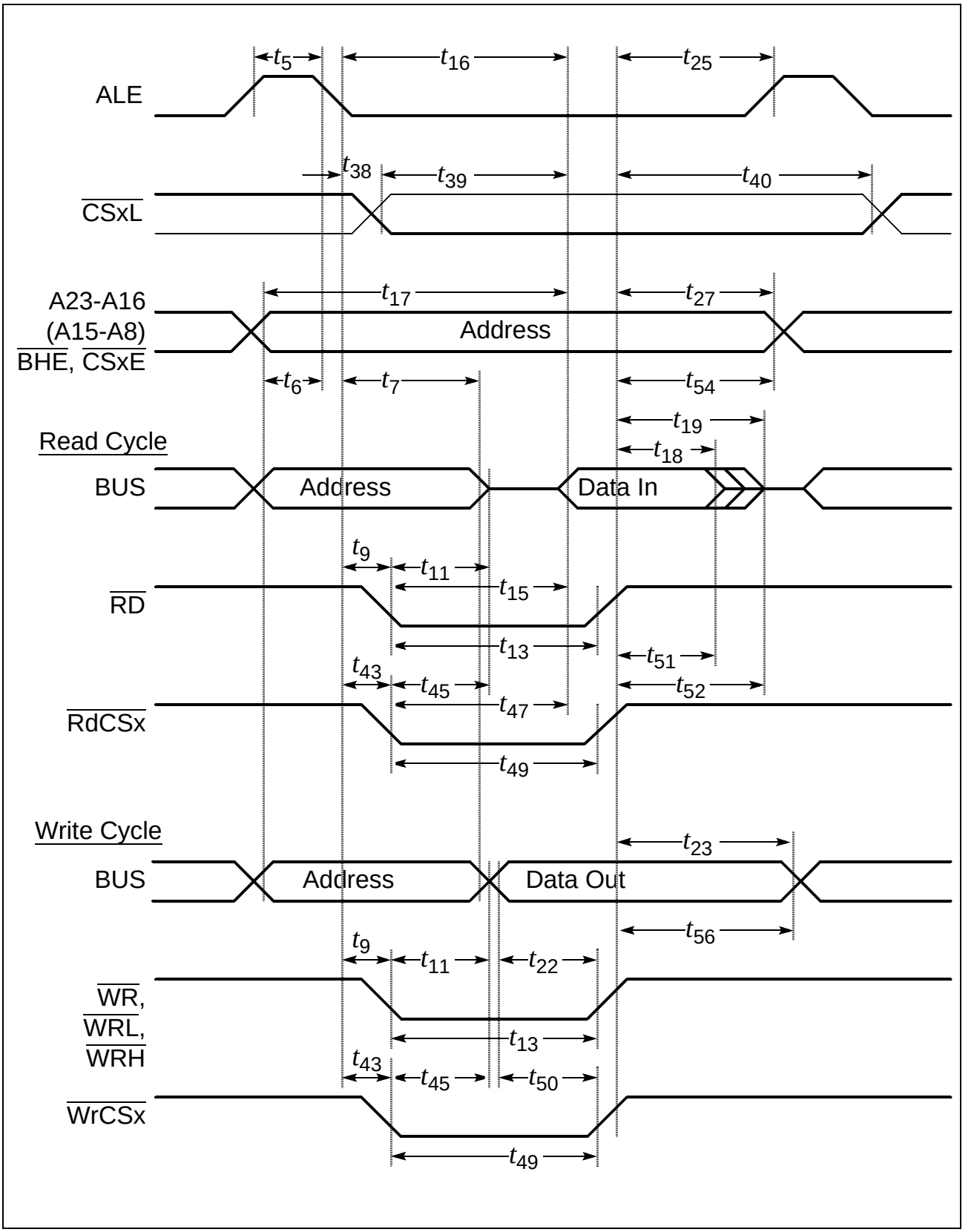


Figure 15 External Memory Cycle: Multiplexed Bus, No Read/Write Delay, Normal ALE

AC Characteristics

Demultiplexed Bus (Standard Supply Voltage Range)

(Operating Conditions apply)

ALE cycle time = 4 TCL + 2t_A + t_C + t_F (80 ns at 25 MHz CPU clock without waitstates)

Parameter	Symbol		Max. CPU Clock = 25 MHz		Variable CPU Clock 1 / 2TCL = 1 to 25 MHz		Unit
			min.	max.	min.	max.	
ALE high time	t_5	CC	10 + t_A	–	TCL - 10 + t_A	–	ns
Address setup to ALE	t_6	CC	4 + t_A	–	TCL - 16 + t_A	–	ns
ALE falling edge to $\overline{RD}$, $\overline{WR}$ (with RW-delay)	t_8	CC	10 + t_A	–	TCL - 10 + t_A	–	ns
ALE falling edge to $\overline{RD}$, $\overline{WR}$ (no RW-delay)	t_9	CC	- 10 + t_A	–	- 10 + t_A	–	ns
$\overline{RD}$, $\overline{WR}$ low time (with RW-delay)	t_{12}	CC	30 + t_C	–	2TCL - 10 + t_C	–	ns
$\overline{RD}$, $\overline{WR}$ low time (no RW-delay)	t_{13}	CC	50 + t_C	–	3TCL - 10 + t_C	–	ns
$\overline{RD}$ to valid data in (with RW-delay)	t_{14}	SR	–	20 + t_C	–	2TCL - 20 + t_C	ns
$\overline{RD}$ to valid data in (no RW-delay)	t_{15}	SR	–	40 + t_C	–	3TCL - 20 + t_C	ns
ALE low to valid data in	t_{16}	SR	–	40 + t_A + t_C	–	3TCL - 20 + t_A + t_C	ns
Address to valid data in	t_{17}	SR	–	50 + 2t_A + t_C	–	4TCL - 30 + 2t_A + t_C	ns
Data hold after $\overline{RD}$ rising edge	t_{18}	SR	0	–	0	–	ns
Data float after $\overline{RD}$ rising edge (with RW-delay[1)])	t_{20}	SR	–	26 + 2t_A + t_F[1)]	–	2TCL - 14 + 22t_A + t_F[1)]	ns
Data float after $\overline{RD}$ rising edge (no RW-delay[1)])	t_{21}	SR	–	10 + 2t_A + t_F[1)]	–	TCL - 10 + 22t_A + t_F[1)]	ns

AC Characteristics

Demultiplexed Bus (Reduced Supply Voltage Range)

(Operating Conditions apply)

ALE cycle time = 4 TCL + 2t_A + t_C + t_F (100 ns at 20 MHz CPU clock without waitstates)

Parameter	Symbol		Max. CPU Clock = 20 MHz		Variable CPU Clock 1 / 2TCL = 1 to 20 MHz		Unit
			min.	max.	min.	max.	
ALE high time	t_5	CC	11 + t_A	–	TCL - 14 + t_A	–	ns
Address setup to ALE	t_6	CC	5 + t_A	–	TCL - 20 + t_A	–	ns
ALE falling edge to $\overline{RD}$, $\overline{WR}$ (with RW-delay)	t_8	CC	15 + t_A	–	TCL - 10 + t_A	–	ns
ALE falling edge to $\overline{RD}$, $\overline{WR}$ (no RW-delay)	t_9	CC	- 10 + t_A	–	- 10 + t_A	–	ns
$\overline{RD}$, $\overline{WR}$ low time (with RW-delay)	t_{12}	CC	34 + t_C	–	2TCL - 16 + t_C	–	ns
$\overline{RD}$, $\overline{WR}$ low time (no RW-delay)	t_{13}	CC	59 + t_C	–	3TCL - 16 + t_C	–	ns
$\overline{RD}$ to valid data in (with RW-delay)	t_{14}	SR	–	22 + t_C	–	2TCL - 28 + t_C	ns
$\overline{RD}$ to valid data in (no RW-delay)	t_{15}	SR	–	47 + t_C	–	3TCL - 28 + t_C	ns
ALE low to valid data in	t_{16}	SR	–	45 + t_A + t_C	–	3TCL - 30 + t_A + t_C	ns
Address to valid data in	t_{17}	SR	–	57 + 2t_A + t_C	–	4TCL - 43 + 2t_A + t_C	ns
Data hold after $\overline{RD}$ rising edge	t_{18}	SR	0	–	0	–	ns
Data float after $\overline{RD}$ rising edge (with RW-delay[1)])	t_{20}	SR	–	36 + 2t_A + t_F[1)]	–	2TCL - 14 + 22t_A + t_F[1)]	ns
Data float after $\overline{RD}$ rising edge (no RW-delay[1)])	t_{21}	SR	–	15 + 2t_A + t_F[1)]	–	TCL - 10 + 22t_A + t_F[1)]	ns

Demultiplexed Bus (Reduced Supply Voltage Range) (cont'd)
(Operating Conditions apply)
ALE cycle time = 4 TCL + $2t_A$ + t_C + t_F (100 ns at 20 MHz CPU clock without waitstates)

Parameter	Symbol		Max. CPU Clock = 20 MHz		Variable CPU Clock 1 / 2TCL = 1 to 20 MHz		Unit
			min.	max.	min.	max.	
Data float after $\overline{\text{RdCS}}$ (with RW-delay)[1]	t_{53}	SR	–	30 + t_F	–	2TCL - 20 + $2t_A$ + t_F [1]	ns
Data float after $\overline{\text{RdCS}}$ (no RW-delay)[1]	t_{68}	SR	–	5 + t_F	–	TCL - 20 + $2t_A$ + t_F [1]	ns
Address hold after $\overline{\text{RdCS}}$, $\overline{\text{WrCS}}$	t_{55}	CC	- 16 + t_F	–	- 16 + t_F	–	ns
Data hold after $\overline{\text{WrCS}}$	t_{57}	CC	9 + t_F	–	TCL - 16 + t_F	–	ns

1) RW-delay and t_A refer to the next following bus cycle (including an access to an on-chip X-Peripheral).

2) Read data are latched with the same clock edge that triggers the address change and the rising $\overline{\text{RD}}$ edge. Therefore address changes before the end of $\overline{\text{RD}}$ have no impact on read cycles.

3) These parameters refer to the latched chip select signals ($\overline{\text{CSxL}}$). The early chip select signals ($\overline{\text{CSxE}}$) are specified together with the address and signal $\overline{\text{BHE}}$ (see figures below).

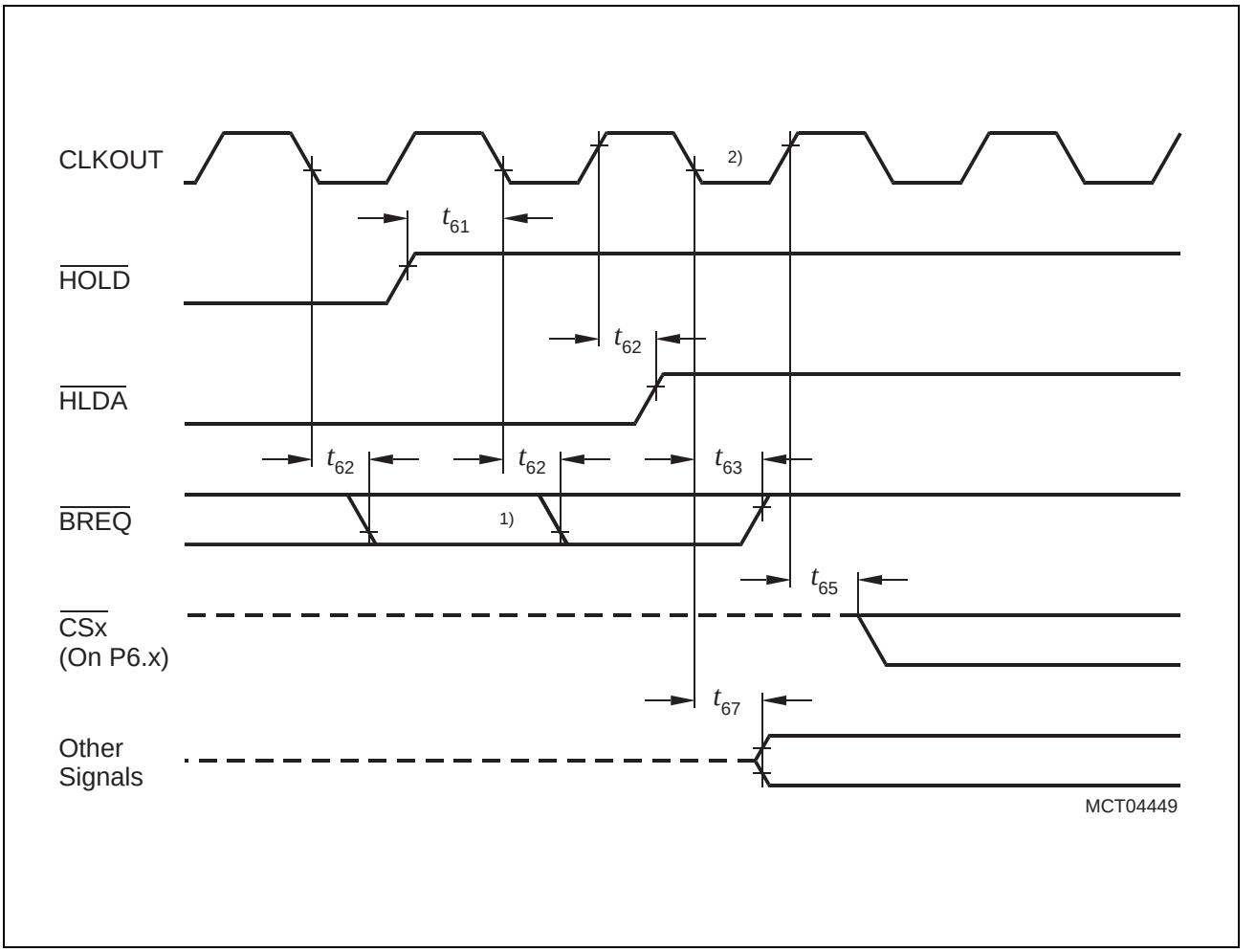


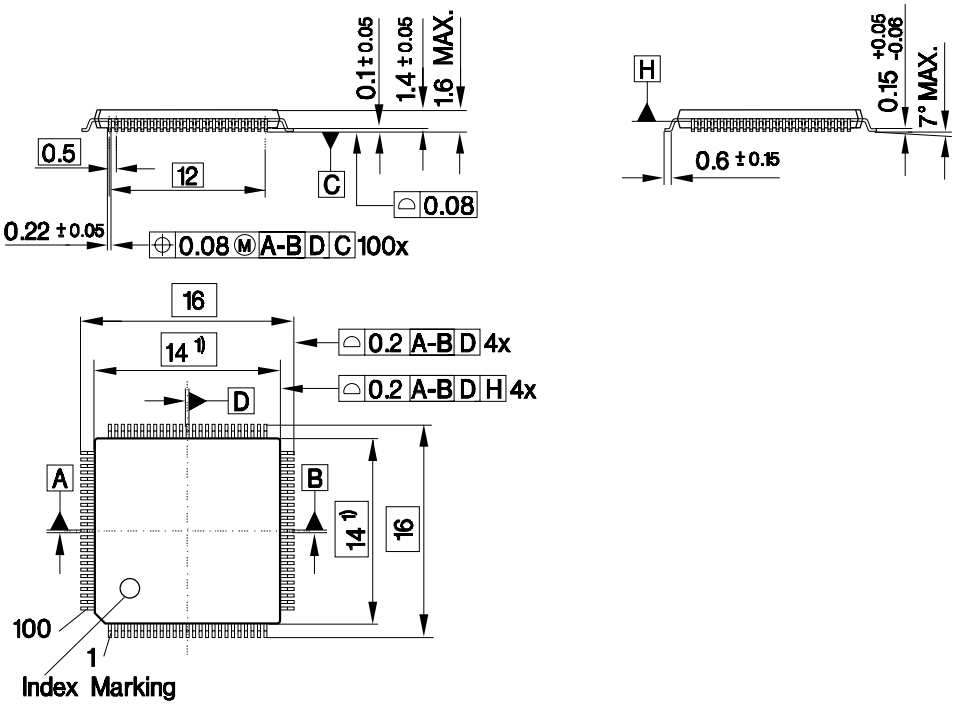
Figure 23 External Bus Arbitration, (Regaining the Bus)

Notes

1) This is the last chance for $\overline{\text{BREQ}}$ to trigger the indicated regain-sequence.
Even if $\overline{\text{BREQ}}$ is activated earlier, the regain-sequence is initiated by $\overline{\text{HOLD}}$ going high.
Please note that $\overline{\text{HOLD}}$ may also be deactivated without the C165 requesting the bus.

2) The next C165 driven bus cycle may start here.

P-TQFP-100 (SMD)
(Plastic Thin Metric Quad Flat Package)



1) Does not include plastic or metal protrusion of 0.25 max. per side

GPP05614

Sorts of Packing
Package outlines for tubes, trays etc. are contained in our Data Book “Package Information”.

SMD = Surface Mounted Device

Dimensions in mm